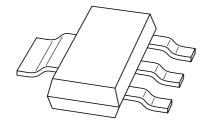
DISCRETE SEMICONDUCTORS

DATA SHEET



BAT120 seriesSchottky barrier double diodes

Product specification
File under Discrete Semiconductors, SC01

1998 Jan 21





Schottky barrier double diodes

BAT120 series

FEATURES

- Low switching losses
- Capability of absorbing very high surge current
- · Fast recovery time
- · Guard ring protected
- · Plastic SMD package.

APPLICATIONS

- Low power switched-mode power supplies
- Rectification
- · Polarity protection.

DESCRIPTION

Planar Schottky barrier double diodes encapsulated in a SOT223 plastic SMD package

MARKING

TYPE NUMBER	MARKING CODE
BAT120A	AT120A
BAT120C	AT120C
BAT120S	AT120S

PINNING

PIN	BAT120						
FIN	Α	С	S				
1	k ₁	a ₁	a ₁				
2	n.c.	n.c.	n.c.				
3	k ₂	a ₂	k ₂				
4	a ₁ , a ₂	k ₁ , k ₂	k ₁ , a ₂				

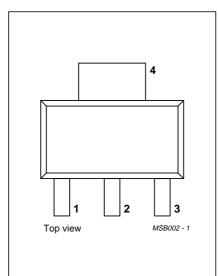


Fig.1 Simplified outline (SOT223) and pin configuration.

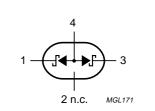
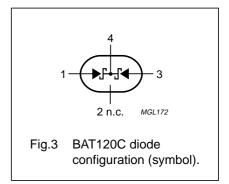


Fig.2 BAT120A diode configuration (symbol).



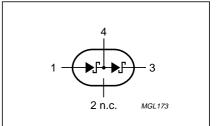


Fig.4 BAT120S diode configuration (symbol).

Schottky barrier double diodes

BAT120 series

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per diode		,			
V _R	continuous reverse voltage		_	25	V
I _F	continuous forward current		_	1	Α
I _{FSM}	non-repetitive peak forward current	t _p < 10 ms; half sinewave; JEDEC method	_	10	А
I _{RSM}	non-repetitive peak reverse current	t _p = 100 ms	_	0.5	Α
T _{stg}	storage temperature		-65	+150	°C
T _j	junction temperature		_	125	°C
T _{amb}	operating ambient temperature		-65	+125	°C

ELECTRICAL CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
Per diode		·		•	•
V _F	forward voltage	see Fig.5			
		I _F = 100 mA	260	300	mV
		I _F = 1 A	400	450	mV
I _R reverse current		V _R = 20 V; note 1; see Fig.6	80	500	mA
		V _R = 25 V; note 1; see Fig.6	_	1000	mA
		$V_R = 20 \text{ V}; T_j = 100 ^{\circ}\text{C}; \text{ note } 1$	_	10	mA
C _d	diode capacitance	$f = 1 \text{ MHz}$; $V_R = 4 \text{ V}$; see Fig.7	100	_	pF

Note

1. Pulsed test: $t_p = 300 \ \mu s$; $\delta = 0.02$.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	note 1	100	K/W

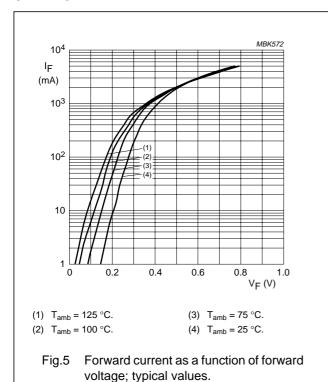
Note

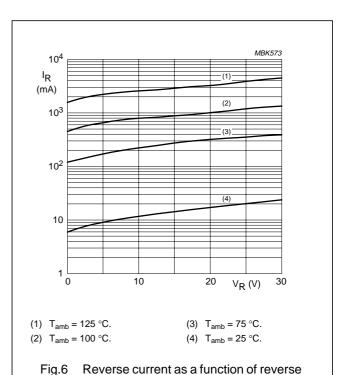
1. Refer to SOT223 standard mounting conditions.

Schottky barrier double diodes

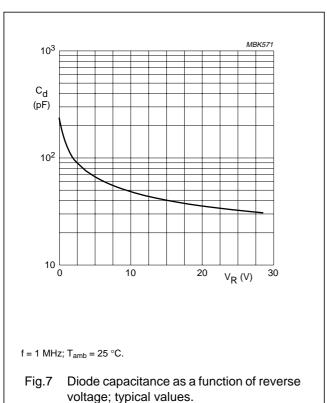
BAT120 series

GRAPHICAL DATA





voltage; typical values.



voltage; typical values.

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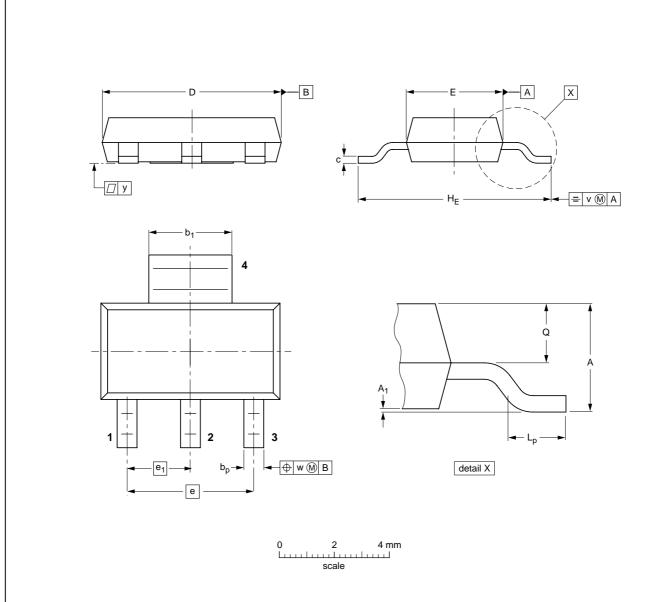
Schottky barrier double diodes

BAT120 series

PACKAGE OUTLINE

Plastic surface mounted package; collector pad for good heat transfer; 4 leads

SOT223



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁	bp	b ₁	С	D	E	е	e ₁	HE	Lp	Q	٧	w	у
mm	1.8 1.5	0.10 0.01	0.80 0.60	3.1 2.9	0.32 0.22	6.7 6.3	3.7 3.3	4.6	2.3	7.3 6.7	1.1 0.7	0.95 0.85	0.2	0.1	0.1

OUTLINE		EUROPEAN	ICCUE DATE				
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT223						96-11-11 97-02-28	

Schottky barrier double diodes

BAT120 series

DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

Schottky barrier double diodes

BAT120 series

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